



US2A THRU US2M

SURFACE MOUNT ULTRA FAST RECTIFIER

Reverse Voltage - 50 to 1000 Volts Forward Current - 2.0 Amperes

FEATURES

The plastic package carries Underwriters Laboratory
 Flammability Classification 94V-0
 For surface mounted applications
 Ultra fast switching for high efficiency
 Low reverse leakage
 Built-in strain relief, ideal for automated placement
 High forward surge current capability
 High temperature soldering guaranteed
 260 C/10 seconds at terminals
 Glass passivated chip junction

MECHANICAL DATA

Case: JEDEC DO-214AA molded plastic body over passivated chip

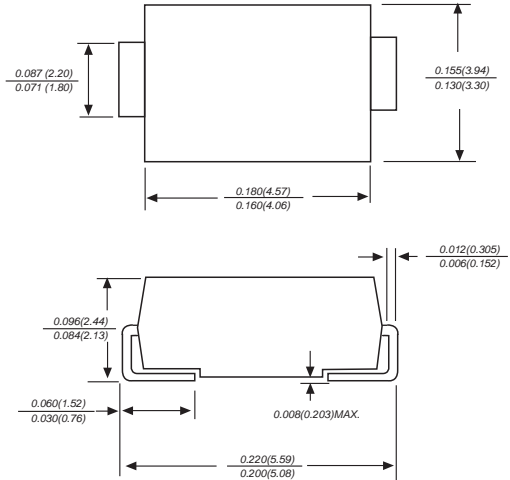
Terminals: Solder plated, solderable per MIL-STD-750,
 Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.003 ounce, 0.093 grams

DO-214AA



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

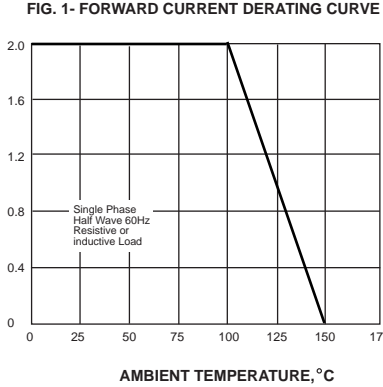
	SYMBOLS	US2A	US2B	US2D	US2G	US2J	US2K	US2M	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	VOLTS
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	VOLTS
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	VOLTS
Maximum average forward rectified current at $T_L=100^\circ\text{C}$	$I_{(AV)}$	2.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	50.0							Amps
Maximum instantaneous forward voltage at 2.0A	V_F	1.0		1.4		1.7		Volts	
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=125^\circ\text{C}$	I_R	5.0 100.0							μA
Maximum reverse recovery time (NOTE 1)	t_{rr}	50				75			ns
Typical junction capacitance (NOTE 2)	C_J	20.0							pF
Typical thermal resistance (NOTE 3)	$R_{\theta JA}$	50.0							$^\circ\text{C/W}$
Operating junction and storage temperature range	T_J, T_{STG}	-65 to +150							$^\circ\text{C}$

Note: 1. Reverse recovery condition $I_F=0.5\text{A}, I_R=1.0\text{A}, I_{rr}=0.25\text{A}$
 2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
 3. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

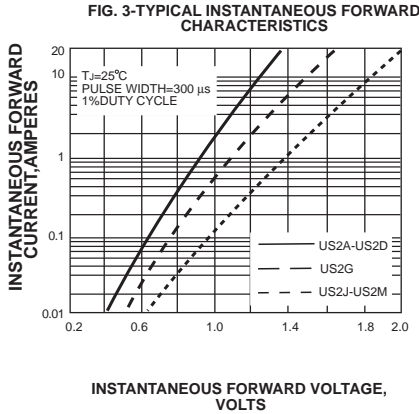
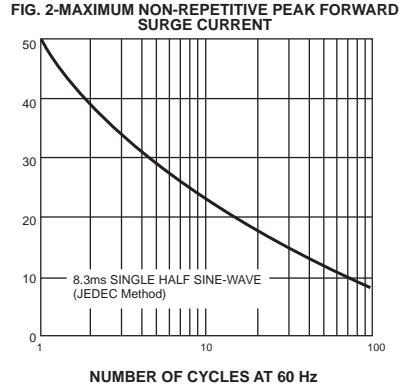


RATINGS AND CHARACTERISTIC CURVES US2A THRU US2M

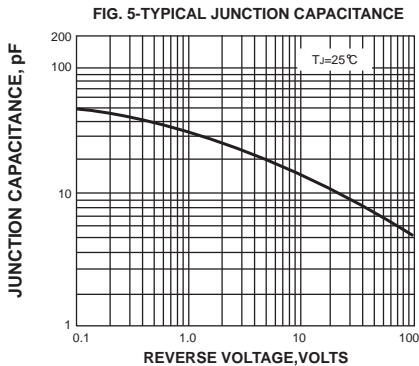
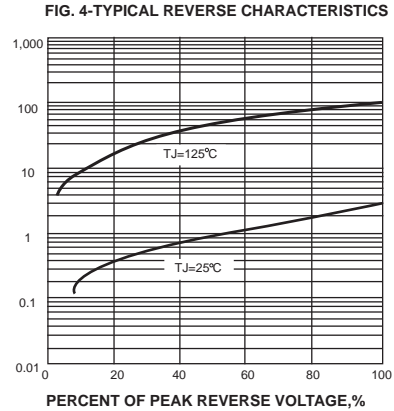
AVERAGE FORWARD RECTIFIED CURRENT, AMPERES



PEAK FORWARD SURGE CURRENT, AMPERES



INSTANTANEOUS REVERSE CURRENT, MICROAMPERES



TRANSIENT THERMAL IMPEDANCE, $^{\circ}\text{C}/\text{W}$

